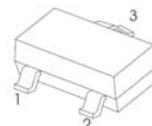


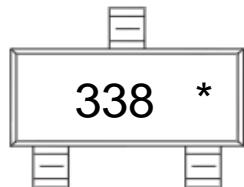
<b>V<sub>(BR)DSS</sub></b>	<b>R<sub>DS(on)MAX</sub></b>	<b>I<sub>D</sub></b>
<b>-20V</b>	200 mΩ@-4.5V	<b>-1.6A</b>
	290 mΩ@-2.5V	

**SOT-23**

**FEATURE**

TrenchFET Power MOSFET

**APPLICATION**

- Load Switch for Portable Devices
- DC/DC Converter

**MARKING**

**Equivalent Circuit**

**Maximum ratings (T<sub>a</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>GS</sub>	±8	
Continuous Drain Current (T <sub>j</sub> =150°C)	I <sub>D</sub>	-1.6	A
Pulsed Drain Current	I <sub>DM</sub>	-10	
Continuous Source-Drain Diode Current	I <sub>S</sub>	-0.72	
Maximum Power Dissipation	P <sub>D</sub>	0.35	
Thermal Resistance from Junction to Ambient(t≤5s)	R <sub>θJA</sub>	357	°C/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature	T <sub>stg</sub>	-55 ~+150	

$T_a=25^\circ\text{C}$  unless otherwise specified    **MOSFET ELECTRICAL CHARACTERISTICS**

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
<b>Static</b>						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = -250\mu\text{A}$	-20			V
Gate-source threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = -250\mu\text{A}$	-0.4		-1	
Gate-source leakage	$I_{\text{GSS}}$	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 8\text{V}$			$\pm 100$	nA
Zero gate voltage drain current	$I_{\text{DSS}}$	$V_{\text{DS}} = -20\text{V}, V_{\text{GS}} = 0\text{V}$			-1	$\mu\text{A}$
Drain-source on-state resistance <sup>a</sup>	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}} = -4.5\text{V}, I_D = -1.6\text{A}$		0.120	0.150	$\Omega$
		$V_{\text{GS}} = -2.5\text{V}, I_D = -1.5\text{A}$		0.160	0.210	
Forward transconductance <sup>a</sup>	$g_{\text{fs}}$	$V_{\text{DS}} = -5\text{V}, I_D = -2.8\text{A}$		4.0		S
<b>Dynamic<sup>b</sup></b>						
Input capacitance	$C_{\text{iss}}$	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		405		pF
Output capacitance	$C_{\text{oss}}$			75		
Reverse transfer capacitance	$C_{\text{rss}}$			55		
Total gate charge	$Q_g$	$V_{\text{DS}} = -10\text{V}, V_{\text{GS}} = -4.5\text{V}, I_D = -3\text{A}$		5.5	10	nC
Gate-source charge	$Q_{\text{gs}}$			3.3	6	
Gate-drain charge	$Q_{\text{gd}}$			0.7		
Gate resistance	$R_g$			1.3		
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -10\text{V}, R_L = 10\Omega, I_D = -1\text{A}, V_{\text{GEN}} = -4.5\text{V}, R_g = 1\Omega$		6.0		$\Omega$
Rise time	$t_r$			11	20	ns
Turn-off delay time	$t_{\text{d}(\text{off})}$			35	60	
Fall time	$t_f$			30	50	
				10	20	
<b>Drain-source body diode characteristics</b>						
Continuous source-drain diode current	$I_S$	$T_C = 25^\circ\text{C}$			-1.3	A
Pulse diode forward current <sup>a</sup>	$I_{\text{SM}}$				-10	
Body diode voltage	$V_{\text{SD}}$	$I_S = -0.7\text{A}$		-0.8	-1.2	V

**Notes :**

a.Pulse Test : Pulse Width < 300μs, Duty Cycle ≤2%.

b.Guaranteed by design, not subject to production testing.

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